

# **Excellent Integrated System Limited**

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

**RFMD** XD010-42S-D4F

For any questions, you can email us directly: sales@integrated-circuit.com

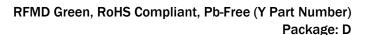
Datasheet of XD010-42S-D4F - MODULE POWER AMP LDMOS 10W A Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



# **XD010-42S-D4F(Y)**

869 MHz to 894 MHz CLASS A

rfmd.com



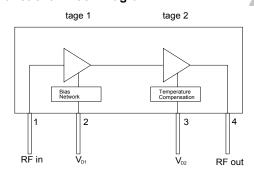


#### **Product Description**

RFMD's XD010-42S-D4F 8W power module is a robust 2-Stage Class A amplifier module for use in the driver stages of linear RF power amplifiers of cellular base stations. The power transistors are fabricated using RFMD's latest, high performance LDMOS process. This unit operated from a single voltage and has internal temperature compensation of the bias voltage to ensure stable performance over the full temperature range. It is internally matched to  $50\,\Omega$ .



#### **Functional Block Diagram**



Case Flange = Ground

#### **Features**

- Available in RoHS Compliant Packaging
- 50Ω RF Impedance
- 8W output P<sub>1dB</sub>
- Single Supply Operation: Nominally 28V
- High Gain: 30dB at 880MHz
- Advanced, XeMOS II LDMOS FETS
- Temperature Compensation

## **Applications**

- Base Station PA Driver
- Repeater
- CDMA
- GSM/EDGE

Parameter		Specification		Unit	Condition
rarameter	Min.	Тур.	Max.	Onit	Condition
Frequency of Operation	869		894	MHz	
Output Power at 1dB Compression	7	8		W	880MHz
Gain	28	30		dB	1W Output Power
Over Frequency		0.4	1	dB	1W Output (CW)
Drain Efficiency	22	24		%	8W CW Output
		3.5		%	1W CDMA (Single Carrier IS-95)
Input Return Loss	14	20		dB	1W Output (CW) 50Ω ref
ACPR at 1W CDMA Power Output		-50		dB	Single Carrier IS-95, 9 Ch FWD, Offset=750 KHz, ACPR Integrated Bandwidth
ALT-1 at 2 W CDMA		-75		dB	Single Carrier IS-95, 9 Ch FWD, Offset=1980 KHz, ACPR Integrated Bandwidth
Third Order IMD	-28	-32		dB	8W PEP (Two Tone; 1MHz)
	-40	-50		dB	1W PEP (Two Tone; 1MHz)
Signal Delay from Pin 1 to Pin 4		3.9		nS	
Deviation from Linear Phase (Peak to Peak)		0.5		Deg	
Thermal Resistance Stage 1 (Junction to Case)		11		°C/W	
Test Conditions: Z <sub>IN</sub> =Z <sub>OUT</sub> =50Ω V <sub>DE</sub>	=28.0V I <sub>C</sub>	001=230mA I <sub>DC</sub>	<sub>2</sub> =700mA T	FLANGE=25°C	1

RF MICRO DEVICES®, RRMD®, Optimum Technology Matching®, Enabling Wireless Connectivity™, PowerStar®, PoLARIS™ TOTAL RADIO™ and UltimateBlue™ are trademarks of RFMD, LLC. BLUETOOTH is a trademark owned by Bluetooth SGI, inc., U.S.A. and licensed for use by RFMD. All other trade names, trademarks and registered trademarks are the property of their respective owners. 2000, RF Mrd. Devices, Inc.

Datasheet of XD010-42S-D4F - MODULE POWER AMP LDMOS 10W A

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

# XD010-42S-D4F(Y)



rfmd.com

#### **Absolute Maximum Ratings**

Parameter	Rating	Unit
1 <sup>st</sup> Stage Bias Voltage (V <sub>D1</sub> )	35	V
2 <sup>nd</sup> Stage Bias Voltage (V <sub>D2</sub> )	35	V
RF Input Power	+20	dBm
Load Impedance for Continuous Operation Without Damage	5:1	VSWR
Output Device Channel Temperature	+200	°C
Operating Temperature Range	-20 to +90	°C
Storage Temperature Range	-40 to +100	°C
ESD Rating - Human Body Model, JEDEC Document - JESD22-A114-B	8000	V
MTTF - 85°C Leadframe, 200°C Channel	1.2×10 <sup>6</sup>	Hours

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one.



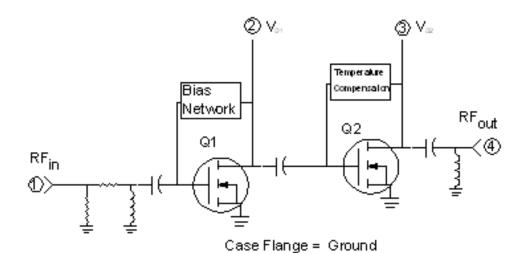
Caution! ESD sensitive device.

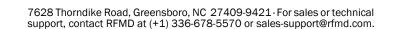
Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EUDirective 2002/95/EC (at time of this document revision).

The information in this publication is believed to be accurate and reliable. However, no responsibility is assumed by RF Micro Devices, Inc. ("RFMD") for its use, nor for any infringement of patents, or other rights of third parties, resulting from its use. No license is granted by implication or otherwise under any patent or patent rights of RFMD. RFMD reserves the right to change component circuitry, recommended application circuitry and specifications at any time without prior notice.

#### **Simplified Device Schematic**





Datasheet of XD010-42S-D4F - MODULE POWER AMP LDMOS 10W A

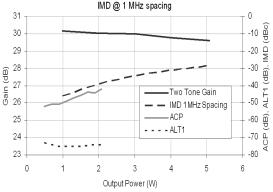
Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

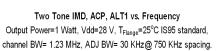


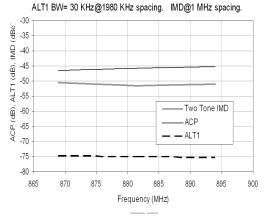
# **XD010-42S-D4F(Y)**

#### **Typical Performance Curves**

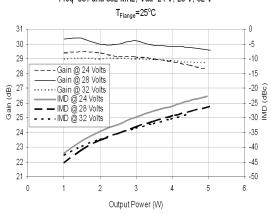
Gain, IMD, ACP, ALT1 vs. Output Power Freq=881 MHz, Vdd=28V, T<sub>Flange</sub>=25°C, IS-95 ADJ BW=30KHz @ 750 KHz spacing ALT1 BW=30KHz @1980 KHz spacing IMD @ 1 MHz spacing



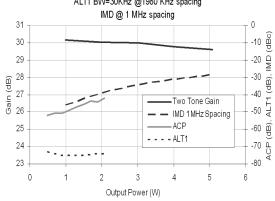




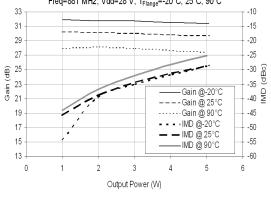
#### Gain and IMDs vs. Output Power and Voltage Freq=881 and 882 MHz, Vdd=24 V, 28 V, 32 V



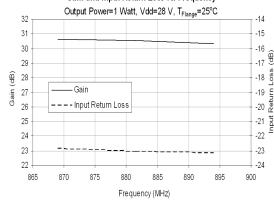
# Gain, IMD, ACP, ALT1 vs. Output Power Freq=881 MHz, Vdd=28V, T<sub>Flange</sub>=25°C, IS-95 ADJ BW=30KHz @ 750 KHz spacing ALT1 BW=30KHz @1980 KHz spacing



## Gain and IMD vs. Output Power and Temperature Freq=881 MHz, Vdd=28 V, T<sub>Flange</sub>=-20°C, 25°C, 90°C



#### Gain and Input Return Loss vs. Frequency



Datasheet of XD010-42S-D4F - MODULE POWER AMP LDMOS 10W A

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

# XD010-42S-D4F(Y)



rfmd.com

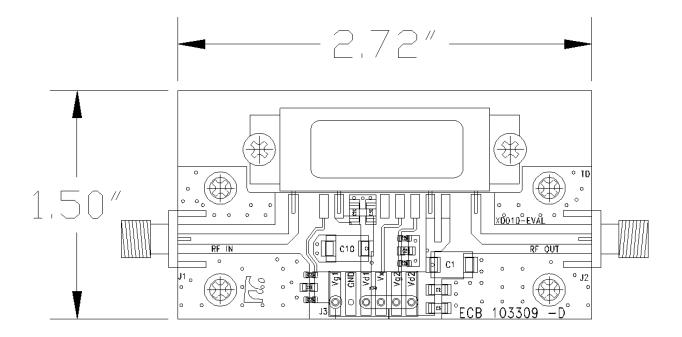
Pin	Function	Description
1	RFIN	Module RF input. This pin is internally connected to DC ground. Do not apply DC voltages to the RF leads. Care must be taken to protect against video transients that may damage the active devices.
2	VD1	This is the drain voltage for the first stage. Nominally +28Vdc
3	VD2	This is the drain voltage for the 2 <sup>nd</sup> stage of the amplifier module. The 2 <sup>nd</sup> stage gate bias is temperature compensated to maintain constant quiescent drain current over the operating temperature range. See Note 1.
4	RFOUT	Module RF output. This pin is internally connected to DC ground. Do not apply DC voltages to the RF leads. Care must be taken to protect against video transients that may damage the active devices.
Flange	GND	Exposed area on the bottom side of the package needs to be mechanically attached to the ground plane of the board for optimum thermal and RF performance. See mounting instructions in application note AN-060 on RFMD's web site.

Note 1: The internally generated gate voltage is thermally compensated to maintain constant quiescent current over the temperature range listed in the data sheet. No compensation is provided for gain changes with temperature. This can only be accomplished with AGC external to the module.

Note 2: Internal RF decoupling is included on all bias leads. No additional bypass elements are required, however some applications may require energy storage on the drain leads to accommodate time-varying waveforms.

Note 3: This module was designed to have its leads hand soldered to an adjacent PCB. The maximum soldering iron tip temperature should not exceed 700° F, and the soldering iron tip should not be in direct contact with the lead for longer than 10 seconds. Refer to app note AN060 (www.RFMD.com) for further installation instructions.

## **Test Board Layout**

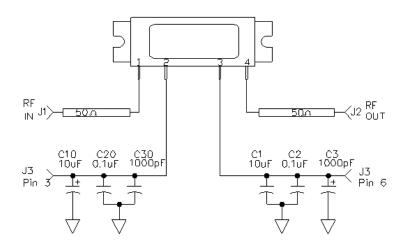


Test Board Schematic with module connections shown

Datasheet of XD010-42S-D4F - MODULE POWER AMP LDMOS 10W A Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

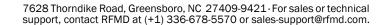


# **XD010-42S-D4F(Y)**



#### **Test Board Bill of Materials**

Description	Manufacture
Rogers 4350, $\varepsilon_{\rm r}$ =3.5, Thickness=30mils	Rogers
SMA, RF, Panel Mount Tab W / Flange	Johnson
MTA Post Header, 6 Pin, Rectangle, Polarized, Surface Mount	AMP
Cap, 10 $\mu$ F, 35V, 10%, Tant, Elect, D	Kemet
Cap, 0.1μF, 100V, 10%, 1206	Johanson
Cap, 1000pF, 100V, 10%, 1206	Johanson
Cap, 68pF, 250V, 5%, 0603	ATC
Cap, 0.1mF, 100V, 10%, 0805	Panasonic
	AVX
4-40 X 0.250"	Various
	SMA, RF, Panel Mount Tab W / Flange MTA Post Header, 6 Pin, Rectangle, Polarized, Surface Mount Cap, $10\mu$ F, 35V, $10\%$ , Tant, Elect, D Cap, $0.1\mu$ F, $100$ V, $10\%$ , $1206$ Cap, $1000$ pF, $100$ V, $10\%$ , $1206$ Cap, $68$ pF, $250$ V, $5\%$ , $0603$



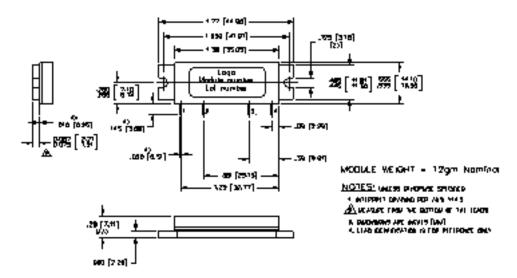


# XD010-42S-D4F(Y)



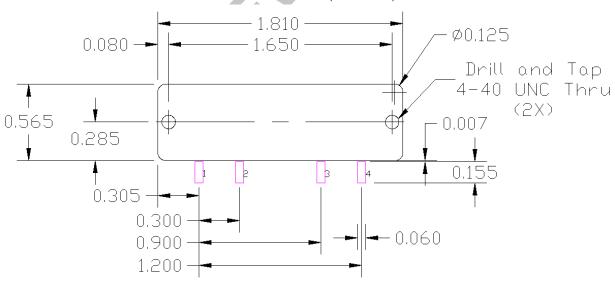
## **Package Outline Drawing**

Dimensions in inches (millimeters)
Refer to drawing posted at www.rfmd.com for tolerances.



## Recommended PCB Cutout and Landing Pads for the D4F Package

Dimensions in inches (millimeters)



Refer to Application note AN-060 "Installation Instructions for XD Module Series" for additional mounting info. App note available at www.RFMD.com.